

# **RJH1CV6DPQ-E0**

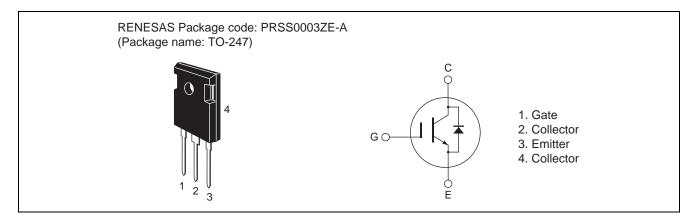
1200V - 30A - IGBT Application: Inverter

R07DS0524EJ0400 Rev.4.00 Jan 19, 2012

#### **Features**

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage  $V_{CE(sat)} = 1.8 \text{ V}$  typ. (at  $I_C = 30 \text{ A}, V_{GE} = 15 \text{ V}, Ta = 25^{\circ}\text{C}$ )
- Built-in fast recovery diode ( $t_{rr} = 200 \text{ ns typ.}$ ) in one package
- Trench gate and thin wafer technology
- High speed switching  $t_f$  = 200 ns typ. (at  $V_{CC}$  = 600 V,  $V_{GE}$  = 15 V,  $I_C$  = 30 A, Rg = 5  $\Omega$ , Ta = 25°C, inductive load)

### **Outline**



### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item		Symbol Ratings		Unit
Collector to emitter voltage / diode reverse voltage		V <sub>CES</sub> / V <sub>R</sub>	1200	V
Gate to emitter voltage		$V_{GES}$	±30	V
Collector current	Tc = 25°C	I <sub>C</sub>	60	А
	Tc = 100°C	I <sub>C</sub>	30	А
Collector peak current		ic(peak) Note1	90	А
Collector to emitter diode forward current		I <sub>DF</sub>	30	А
Collector to emitter diode forward peak current		i <sub>DF</sub> (peak) Note1	90	А
Collector dissipation		P <sub>C</sub> Note2	297.6	W
Junction to case thermal resistance (IGBT)		θj-c Note2	0.42	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at Tc = 25°C

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## **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

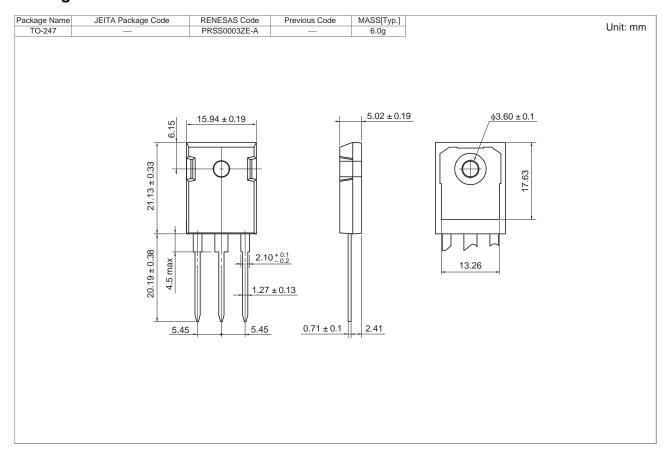
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current	I <sub>CES</sub> /I <sub>R</sub>	_	_	5	μΑ	$V_{CE} = 1200 \text{ V}, V_{GE} = 0$
/ Diode reverse current						
Gate to emitter leak current	I <sub>GES</sub>	_	—	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$
Gate to emitter cutoff voltage	$V_{GE(off)}$	4	_	8	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	_	1.8	_	V	$I_C = 30 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
Input capacitance	Cies	_	1600	_	pF	V <sub>CE</sub> = 25 V
Output capacitance	Coes	_	60	_	pF	V <sub>GE</sub> = 0 f = 1 MHz
Reveres transfer capacitance	Cres	_	35	_	pF	
Switching time	t <sub>d(on)</sub>	_	45	_	ns	$V_{CC} = 600 \text{ V}, V_{GE} = 15 \text{ V}$
	t <sub>r</sub>	_	15	_	ns	$I_C = 30 \text{ A}$ $Rg = 5 \Omega$ Inductive load
	t <sub>d(off)</sub>	_	100	_	ns	
	t <sub>f</sub>	_	200	_	ns	
Short circuit withstand time	t <sub>sc</sub>	_	5	_	μS	$V_{CC} \le 720 \text{ V}, V_{GE} = 15 \text{ V}$ $Tc \le 125^{\circ}C$

FRD forward voltage	$V_{F}$	_	1.7	_	V	I <sub>F</sub> = 30 A <sup>Note3</sup>
FRD reverse recovery time	t <sub>rr</sub>	_	200	_	ns	I <sub>F</sub> = 30 A
						$di_F/dt = 100 A/\mu s$

Notes: 3. Pulse test.

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## **Package Dimension**



# **Ordering Information**

Orderable Part Number	Quantity	Shipping Container
RJH1CV6DPQ-E0#T2	450 pcs	Box (Tube)

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